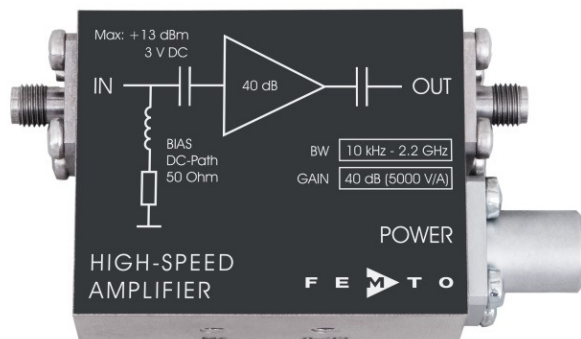




## Datasheet

## HSA-X-I-2-40

### 2.2 GHz High-Speed Amplifier



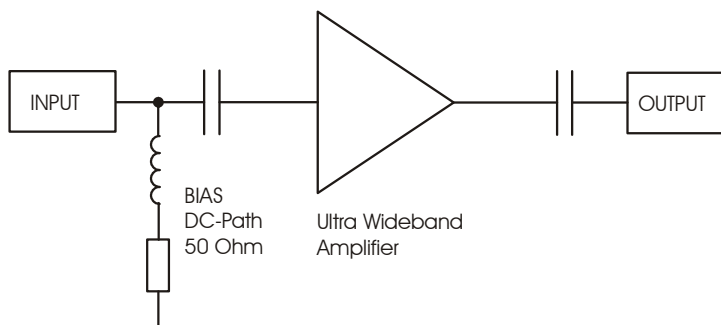
#### Features

- **Bandwidth 10 kHz ... 2.2 GHz**
- **Rise time 160 ps**
- **Gain 40 dB (inverting)**
- **Integrated bias circuit**

#### Applications

- **Preamplifier for ultra-fast detectors (microchannel-plates, photomultipliers, avalanche-photodiodes and PIN-photodiodes)**
- **Oscilloscope and transient-recorder preamplifier**
- **Time-resolved pulse and transient measurements**

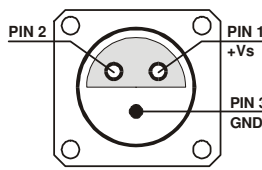
#### Block Diagram

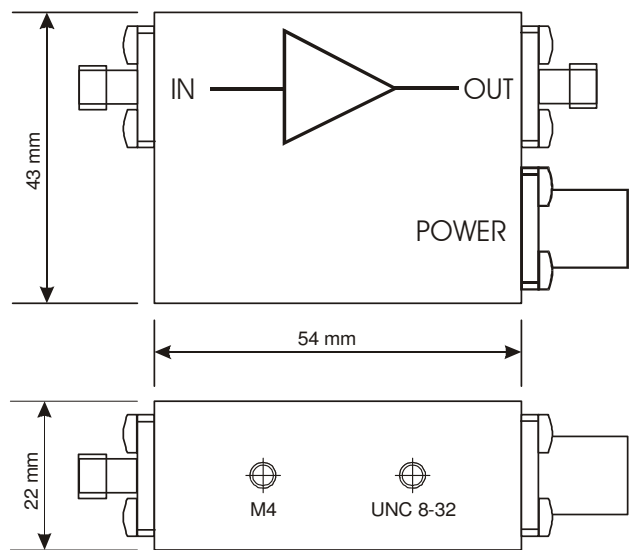


#### Specifications

Test conditions		$V_s = +15\text{ V}$ , $T_A = 25^\circ\text{C}$ , System Impedance = 50 $\Omega$	
Gain	Gain	40 dB	(inverting)
	Gain accuracy	$\pm 1$ dB	
	Frequency Response	Lower cut-off frequency (-3 dB)	10 kHz ( $\pm 20\%$ )
	Upper cut-off frequency (-3 dB)	2.2 GHz ( $\pm 15\%$ )	
	Rise/fall time (10% - 90%)	160 ps	
Input	DC input impedance	50 $\Omega$	
	RF input impedance	50 $\Omega$	
	50 $\Omega$ noise figure	5.1 dB	(@ $f < 1\text{ GHz}$ )
	Equivalent input voltage noise	670 pV/ $\sqrt{\text{Hz}}$	
	Input VSWR	1.25 : 1	(@ $f < 2.2\text{ GHz}$ )
	Input return loss	19 dB	(@ $f < 2.2\text{ GHz}$ )
Output	Output impedance	50 $\Omega$	
	Output power $P_{1\text{dB}}$	+12.5 dBm	(@ $f < 1\text{ GHz}$ )
	Output peak-to-peak voltage	2.0 $V_{pp}$	(@ $f < 500\text{ MHz}$ , for linear amplification)

## 2.2 GHz High-Speed Amplifier

Specifications (continued)	<table border="0"> <tr> <td>Power Supply</td> <td>Supply voltage</td> <td>+15 V</td> </tr> <tr> <td></td> <td>Supply current</td> <td>+145 mA</td> </tr> <tr> <td>Case</td> <td>Weight</td> <td>100 g (0.23 lbs)</td> </tr> <tr> <td></td> <td>Material</td> <td>AlMg4.5Mn, nickel-plated</td> </tr> <tr> <td>Temperature Range</td> <td>Storage temperature</td> <td>-40 ... +100 °C</td> </tr> <tr> <td></td> <td>Operating ambient temperature</td> <td>0 ... +60 °C</td> </tr> </table>	Power Supply	Supply voltage	+15 V		Supply current	+145 mA	Case	Weight	100 g (0.23 lbs)		Material	AlMg4.5Mn, nickel-plated	Temperature Range	Storage temperature	-40 ... +100 °C		Operating ambient temperature	0 ... +60 °C
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Dimensions	 <p style="text-align: right;">DZ01-0601-10</p>
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